

μ A733 Differential Video Amplifier

Linear Division Special Functions

Description

The μ A733 is a monolithic two-stage differential input, differential output video amplifier constructed using the Fairchild Planar Epitaxial process. Internal series shunt feedback is used to obtain wide bandwidth, low phase distortion, and excellent gain stability. Emitter follower outputs enable the device to drive capacitive loads and all stages are current source biased to obtain high power supply and common mode rejection ratios. It offers fixed gains of 10, 100 or 400 without external components, and adjustable gains from 10 to 400 by the use of a single external resistor. No external frequency compensation components are required for any gain option. The device is particularly useful in magnetic tape or disc file systems using phase or NRZ encoding and in high speed thin film or plated wire memories. Other applications include general purpose video and pulse amplifiers where wide bandwidth, low phase shift, and excellent gain stability are required.

- 120 MHz Bandwidth Typ
- 250 k Ω Input Resistance Typ
- Selectable Gains Of 10, 100, And 400
- No Frequency Compensation Required

Absolute Maximum Ratings

Storage Temperature Range

Metal Can and Ceramic DIP -65°C to +175°C

Molded DIP and SO-14 -65°C to +150°C

Operating Temperature Range

Extended (μ A733M) -55°C to +125°C

Commercial (μ A733C) 0°C to +70°C

Lead Temperature

Metal Can and Ceramic DIP
(soldering, 60 s) 300°C

Molded DIP and SO-14
(soldering, 10 s) 265°C

Internal Power Dissipation^{1, 2}

10L-Metal Can 1.07 W

14L-Ceramic DIP 1.36 W

14L-Molded DIP 1.04 W

SO-14 0.93 W

Supply Voltage ± 8.0 V

Differential Input Voltage ± 5.0 V

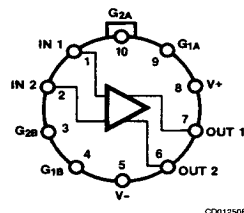
Common Mode Input Voltage ± 6.0 V

Output Current 10 mA

Notes

1. T_J Max = 150°C for the Molded DIP, and 175°C for the Metal Can and Ceramic DIP.
2. Ratings apply to ambient temperature at 25°C. Above this temperature, derate the 10L-Metal Can at 7.1 mW/°C, the 14L-Ceramic DIP at 9.1 mW/°C, the 14L-Molded DIP at 8.3 mW/°C, and the SO-14 at 7.5 mW/°C.

Connection Diagram 10-Lead Metal Package (Top View)



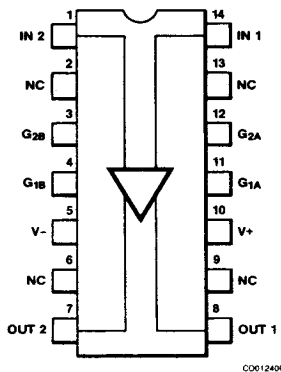
Note

Pin 5 connected to case.

Order Information

Device Code	Package Code	Package Description
μ A733HM	5X	Metal
μ A733HC	5X	Metal

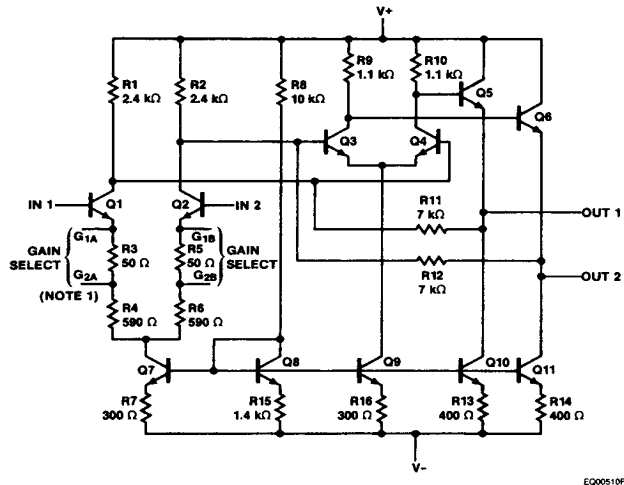
Connection Diagram 14-Lead DIP and SO-14 Package (Top View)



Order Information

Device Code	Package Code	Package Description
μ A733DM	6A	Ceramic DIP
μ A733DC	6A	Ceramic DIP
μ A733PC	9A	Molded DIP
μ A733SC	KD	Molded Surface Mount

Equivalent Circuit



μA733 and μA733C

Electrical Characteristics $T_A = 25^\circ\text{C}$, $V_{CC} = \pm 6.0\text{ V}$ unless otherwise specified.

Symbol	Characteristic	Condition ¹		μA733			μA733C			Unit
				Min	Typ	Max	Min	Typ	Max	
A _{VD}	Differential Voltage Gain		Gain 1	300	400	500	250	400	600	V/V
			Gain 2	90	100	110	80	100	120	
			Gain 3	9.0	10	11	8.0	10	12	
BW	Bandwidth	R _S = 50 Ω	Gain 1		40			40		MHz
			Gain 2		90			90		
			Gain 3		120			120		
t _r	Risetime	R _S = 50 Ω, V _O = 1.0 V _{P-P}	Gain 1		10.5			10.5		ns
			Gain 2		4.5	10		4.5	12	
			Gain 3		2.5			2.5		
t _{PD}	Propagation Delay	R _S = 50 Ω, V _O = 1.0 V _{P-P}	Gain 1		7.5			7.5		ns
			Gain 2		6.0	10		6.0	10	
			Gain 3		3.6			3.6		
Z _I	Input Impedance		Gain 1		4.0			4.0		kΩ
			Gain 2	20	30		10	30		
			Gain 3		250			250		
C _I	Input Capacitance		Gain 2		2.0			2.0		pF
I _{IO}	Input Offset Current				0.4	3.0		0.4	5.0	μA

μA733 and μA733C (Cont.)**Electrical Characteristics** $T_A = 25^\circ\text{C}$, $V_{CC} = \pm 6.0\text{ V}$ unless otherwise specified.

Symbol	Characteristic	Condition ¹	μA733			μA733C			Unit
			Min	Typ	Max	Min	Typ	Max	
I_{IB}	Input Bias Current			9.0	20		9.0	30	μA
e_n	Input Noise Voltage	$R_S = 50\ \Omega$, BW = 1.0 kHz to 10 MHz		12			12		μV _{rms}
V_{IR}	Input Voltage Range		± 1.0			± 1.0			V
CMR	Common Mode Rejection	$V_{CM} = \pm 1.0\text{ V}$, Gain 2	60	86		60	86		dB
PSRR	Supply Voltage Rejection Ratio	$\Delta V_{CC} = \pm 0.5\text{ V}$, Gain 2	50	70		50	70		dB
V_{OS}	Output Offset Voltage	Gain 1		0.6	1.5		0.6	1.5	V
		Gain 2 and Gain 3		0.35	1.0		0.35	1.5	
V_{OCM}	Output Common Mode Voltage		2.4	2.9	3.4	2.4	2.9	3.4	V
V_{OP}	Output Voltage Swing		3.0	4.0		3.0	4.0		V_{p-p}
I_{O-}	Output Sink Current		2.5	3.6		2.5	3.6		mA
R_O	Output Resistance			20			20		Ω
I_{CC}	Supply Current			18	24		18	24	mA

The following specifications apply over the range of $-55^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ for μA733 and $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$ for μA733C.

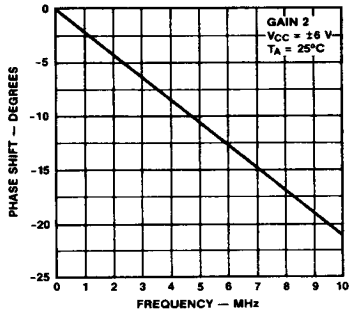
A_{VD}	Differential Voltage Gain	Gain 1	200		600	250		600	V/V
		Gain 2	80		120	80		120	
		Gain 3	8.0		12	8.0		12	
Z_i	Input Impedance	Gain 2	8.0			8.0			kΩ
I_{IO}	Input Offset Current				5.0			6.0	μA
I_{IB}	Input Bias Current				40			40	μA
V_{IR}	Input Voltage Range		± 1.0			± 1.0			V
CMR	Common Mode Rejection		50			50			dB
PSRR	Power Supply Rejection Ratio		50			50			dB
V_{OS}	Output Offset Voltage	Gain 1			1.5			1.5	V
		Gain 2 and Gain 3			1.2			1.5	
V_{OP}	Output Swing		2.5			2.8			V_{p-p}
I_{O-}	Output Sink Current		2.2			2.5			mA
I_{CC}	Supply Current				27			27	mA

Notes

- Gain Select leads G_{1A} and G_{1B} connected together for Gain 1.
- Gain Select leads G_{2A} and G_{2B} connected together for Gain 2.
- All Gain Select leads open for Gain 3.

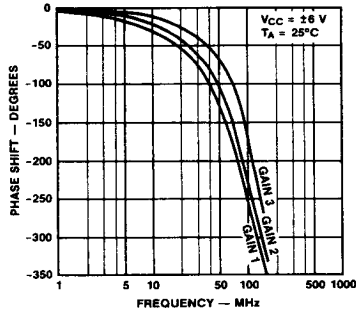
Typical Performance Curves

Phase Shift vs Frequency



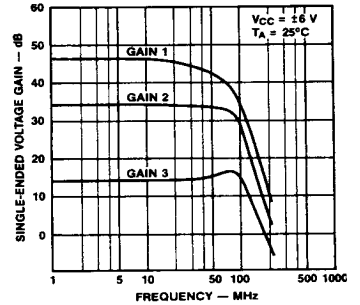
PC07800F

Phase Shift vs Frequency



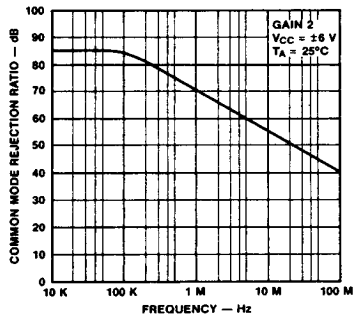
PC07870F

Voltage Gain vs Frequency



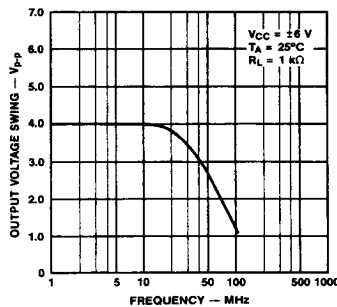
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Common Mode Rejection Ratio vs Frequency



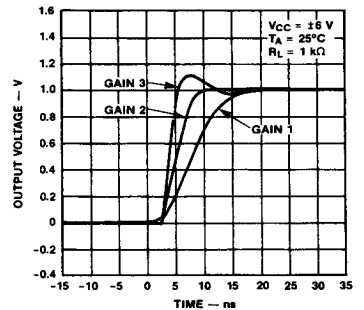
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Output Voltage Swing vs Frequency



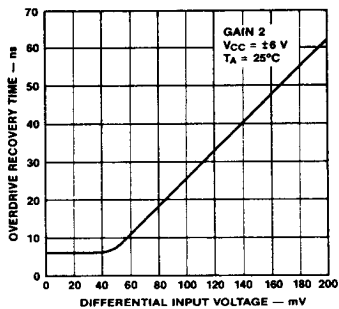
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Pulse Response



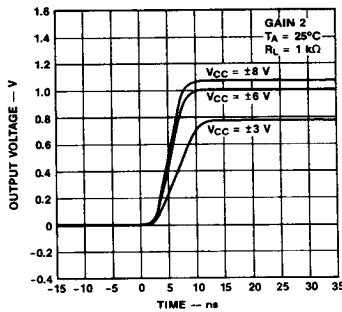
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Differential Overdrive Recovery Time



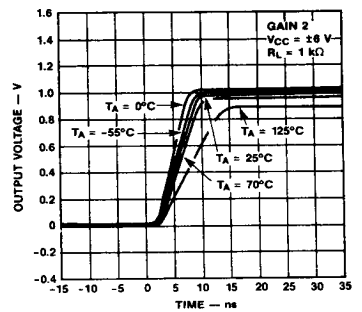
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Pulse Response vs Supply Voltage



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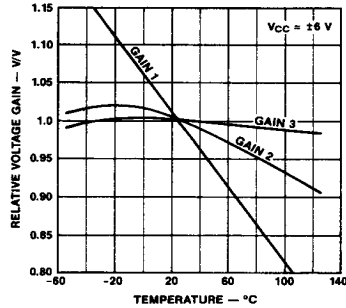
Pulse Response vs Temperature



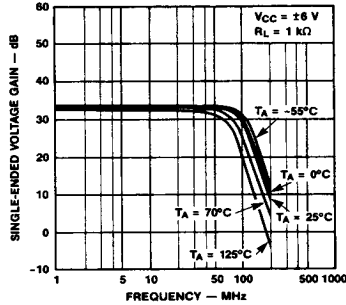
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Typical Performance Curves (Cont.)

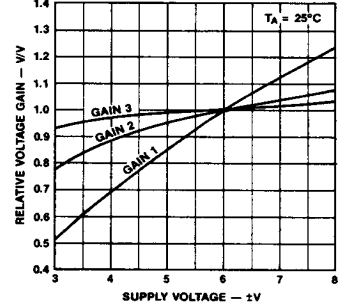
Voltage Gain vs Temperature



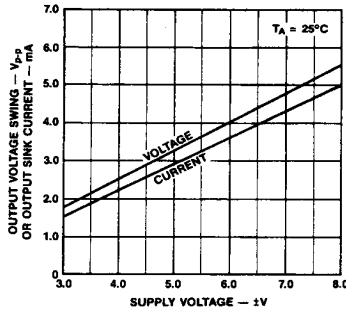
Gain vs Frequency vs Temperature



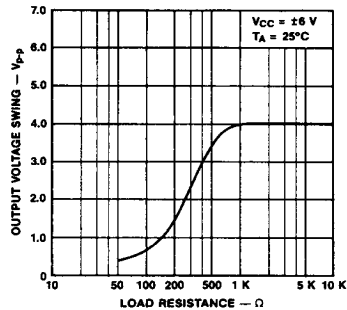
Voltage Gain vs Supply Voltage



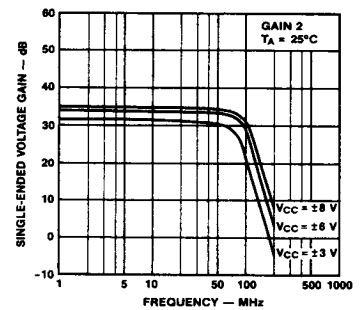
Output Voltage and Current Swing vs Supply Voltage



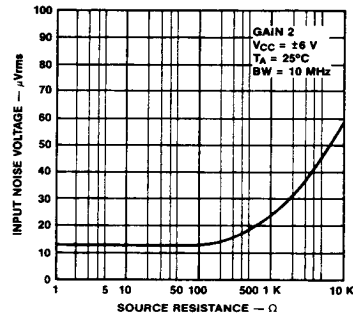
Output Voltage Swing vs Load Resistance



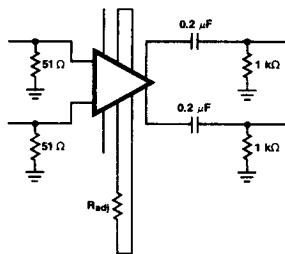
Gain vs Frequency vs Supply Voltage



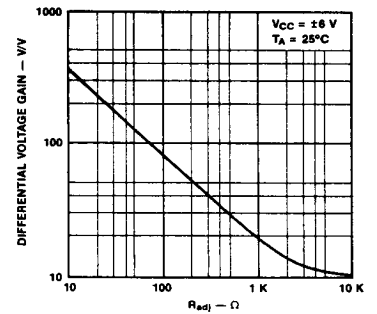
Input Noise Voltage vs Source Resistance



Voltage Gain Adjust Circuit

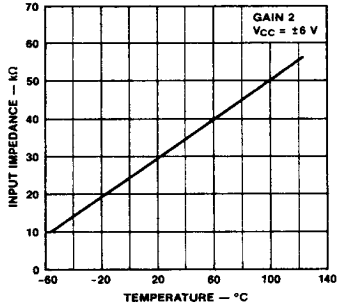


Voltage Gain vs R_{adj}

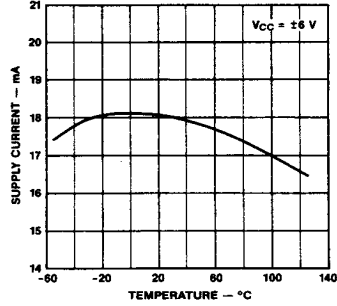


Typical Performance Curves (Cont.)

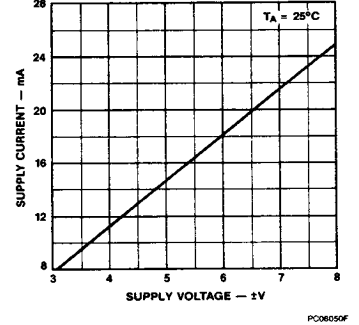
Input Impedance vs Temperature



Supply Current vs Temperature



Supply Current vs Supply Voltage



Typical Applications

Oscillator Frequency for Various Capacitor Values

